

**Product data sheet** 

## 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

## 2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection 1.5 kV HBM
- Drain-source on-state resistance  $R_{DSon}$  = 69 m $\Omega$
- Very low gate-source threshold voltage for portable applications  $V_{GS(th)}$  = -0.68 V

## 3. Applications

- High-side load switch and charging switch for portable devices
- Power management in battery driven portables
- LED driver
- DC-to-DC converter

## 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
V <sub>GS</sub>	gate-source voltage	_		-8	-	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-	-2.9	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -2.9 A; T <sub>j</sub> = 25 °C		-	69	85	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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## 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	4 3	G $\left( \begin{array}{c} \\ \\ \\ \\ \end{array} \right)$
4	D	drain		
			Transparent top view DFN1010D-3 (SOT1215)	S 017aaa259

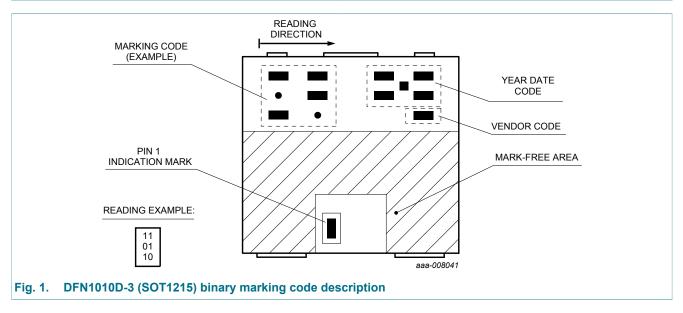
# 6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMXB75UPE	DFN1010D-3	DFN1010D-3: plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm	SOT1215				

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PMXB75UPE	00 01 00



PMXB75UPE

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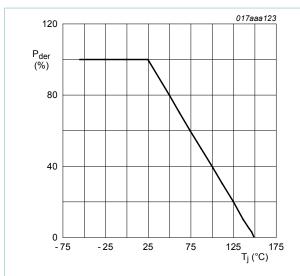
## 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

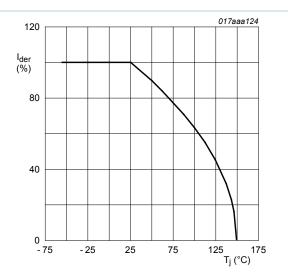
Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-8	8	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	[1]	-	-2.9	А
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 100 °C	[1]	-	-1.9	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-12	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	317	mW
			[1]	-	1070	mW
		T <sub>sp</sub> = 25 °C		-	8330	mW
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-dra	in diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1	А

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.





$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$





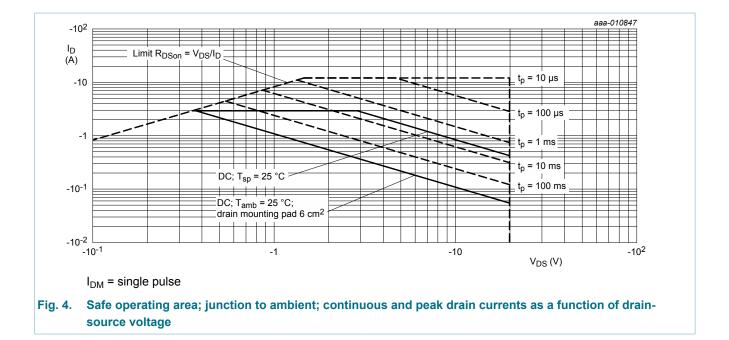
$$I_{der} = \frac{I_D}{I_{D(25^\circ C)}} \times 100 \%$$

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# PMXB75UPE

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## 9. Thermal characteristics

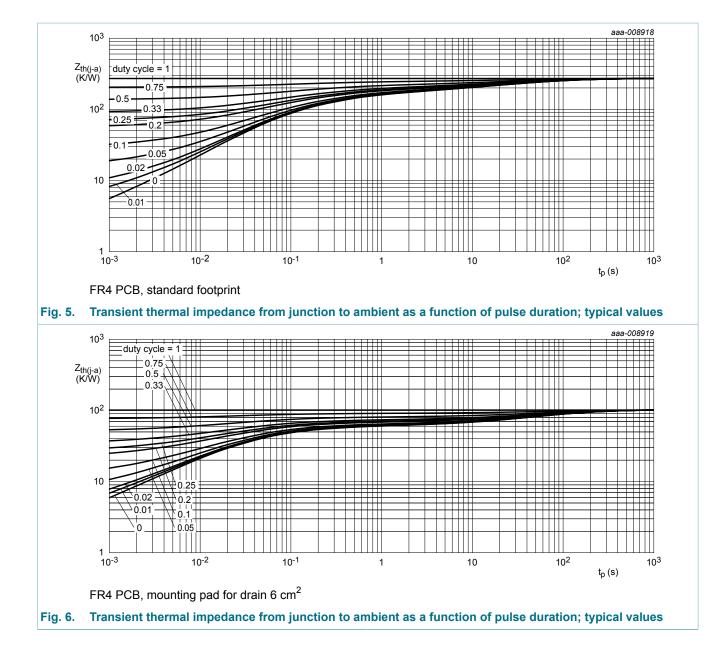
Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance	in free air	[1]	-	271	312	K/W
	from junction to ambient		[2]	-	102	117	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	10	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



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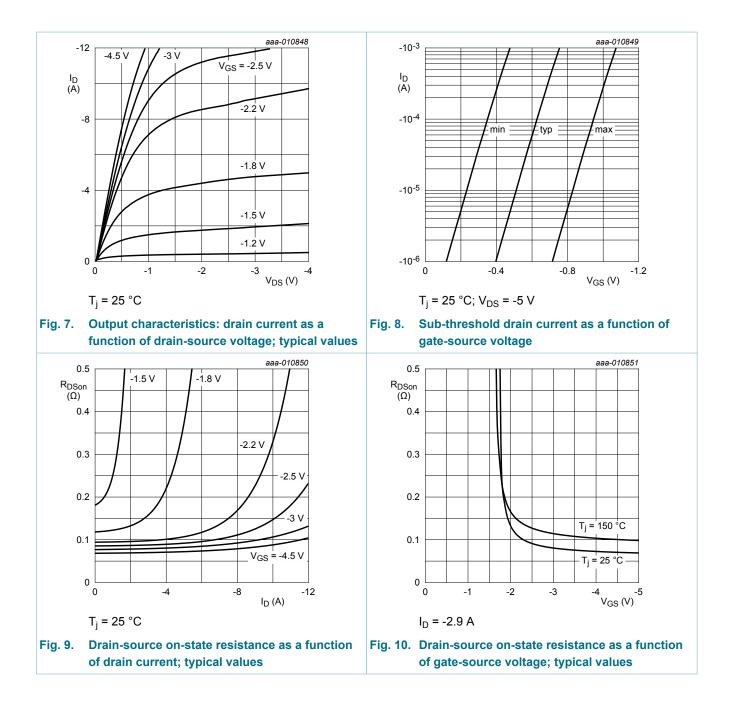


# **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-0.4	-0.68	-1	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = -8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-10	μA
		V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		$V_{GS}$ = -4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
		$V_{GS}$ = 4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	1	μA
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.9 A; T <sub>j</sub> = 25 °C	-	69	85	mΩ
	resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.9 A; T <sub>j</sub> = 150 °C	-	99	122	mΩ
		$V_{GS}$ = -2.5 V; I <sub>D</sub> = -2.6 A; T <sub>j</sub> = 25 °C	-	86	110	mΩ
		$V_{GS}$ = -1.8 V; I <sub>D</sub> = -0.4 A; T <sub>j</sub> = 25 °C	-	130	200	mΩ
		$V_{GS}$ = -1.5 V; I <sub>D</sub> = -50 mA; T <sub>j</sub> = 25 °C	-	205	450	mΩ
		$V_{GS}$ = -1.2 V; I <sub>D</sub> = -10 mA; T <sub>j</sub> = 25 °C	-	950	-	mΩ
9fs	forward transconductance	$V_{DS}$ = -10 V; $I_D$ = -2 A; $T_j$ = 25 °C	-	8.4	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	11.3	-	Ω
Dynamic ch	aracteristics	· · · · · · · · · · · · · · · · · · ·	I			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -10 V; I <sub>D</sub> = -2.9 A; V <sub>GS</sub> = -4.5 V;	-	6.8	12	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.9	-	nC
Q <sub>GD</sub>	gate-drain charge		-	2.1	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = -10 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	608	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	75	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	64	-	pF
d(on)	turn-on delay time	$V_{DS}$ = -10 V; I <sub>D</sub> = -2.9 A; V <sub>GS</sub> = -4.5 V;	-	6	-	ns
r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	19	-	ns
d(off)	turn-off delay time		-	29	-	ns
t <sub>f</sub>	fall time	1	-	15	-	ns
Source-drai	n diode		I		1	
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -1 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.7	-1.2	V

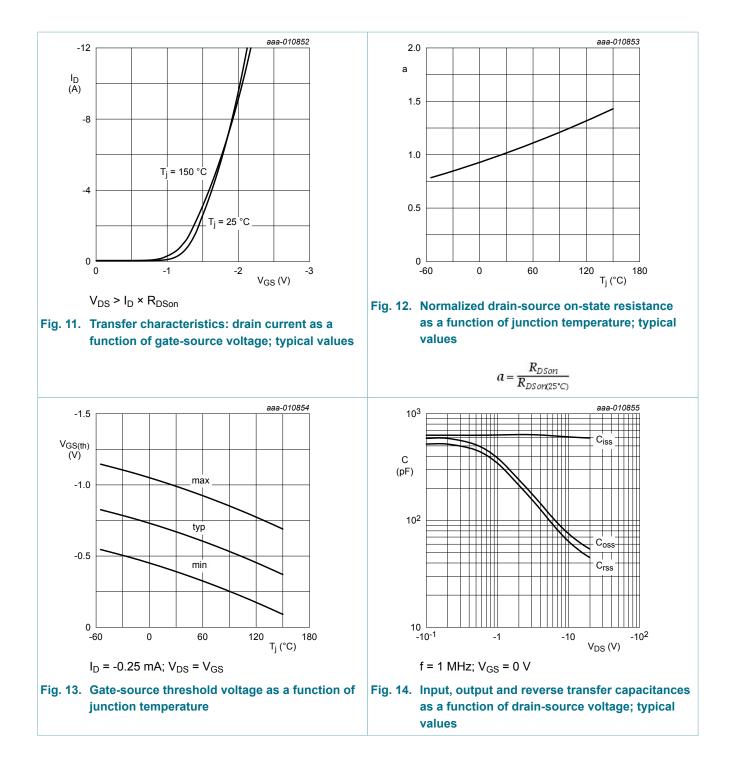
# PMXB75UPE

#### 20 V, P-channel Trench MOSFET



# **PMXB75UPE**

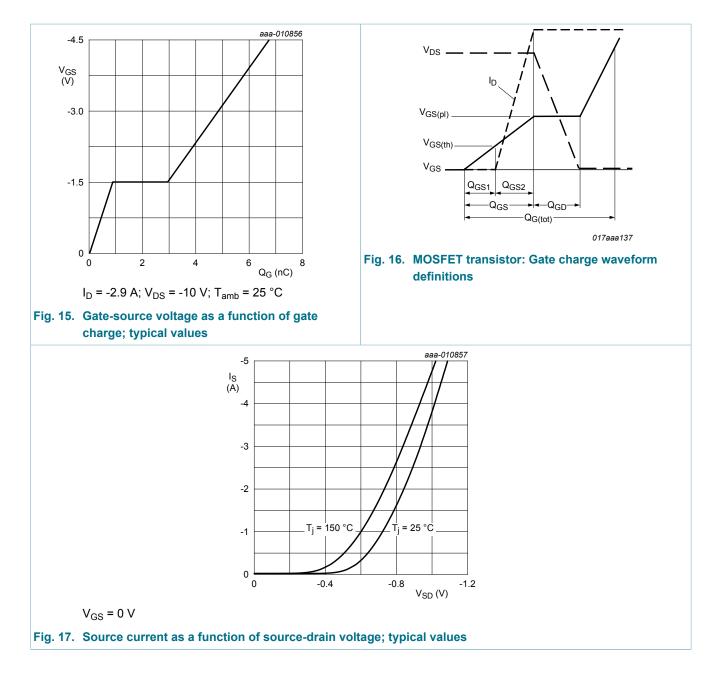
#### 20 V, P-channel Trench MOSFET



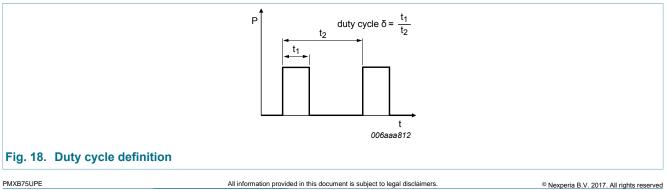
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# PMXB75UPE

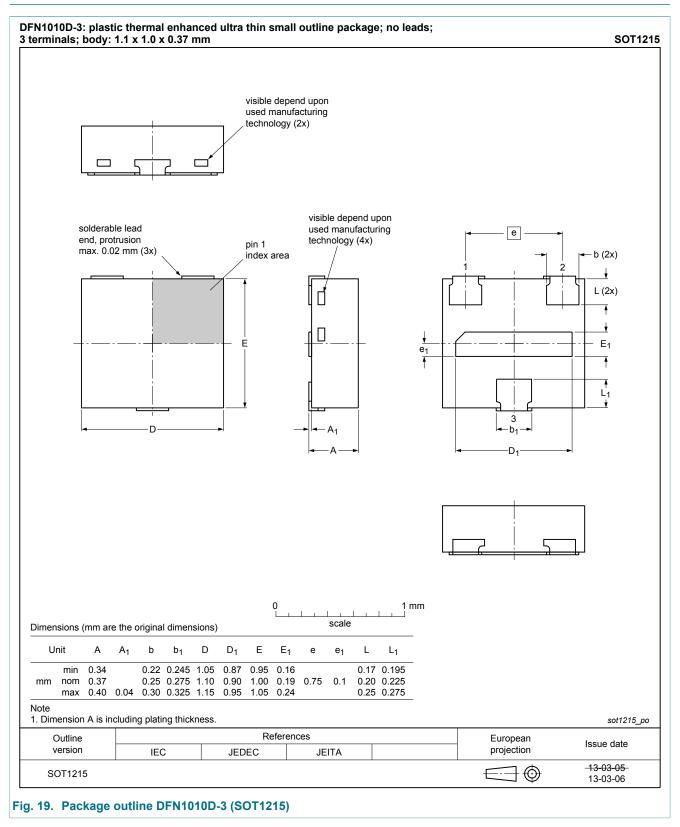
#### 20 V, P-channel Trench MOSFET



# **11. Test information**



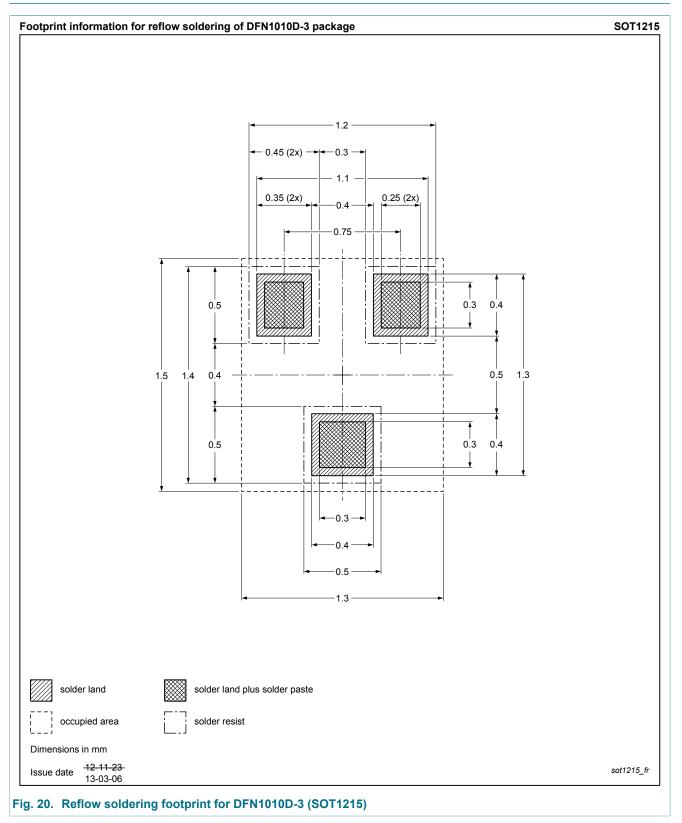
## 12. Package outline



PMXB75UPE

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## **13. Soldering**



# 14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMXB75UPE v.3	20140708	Product data sheet	-	PMXB75UPE v.2
Modifications:	Product status char	nged		
PMXB75UPE v.2	20140218	Preliminary data sheet	-	PMXB75UPE v.1
PMXB75UPE v.1	20140204	Preliminary data sheet	-	-

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#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or [1] completing a design.

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